

Abstract of the Disclosure

A method of fabricating thin film transistor TFT array discloses ions of desired-plated metal and the graphs of the desired-plated
5 area are made by oxidation—reduction materials processes ion replacement for implementing the metal wiring layout of the TFT-LCDs. This, therefore, can overcome the problem of uneasy metal etching thereto achieves the purpose of an automatic alignment. The method uses the ability of the oxidation-reduction
10 reaction to implement the replacement for alternating the lithography etching process in the metal wiring layout as presented in the traditional technique.